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Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China





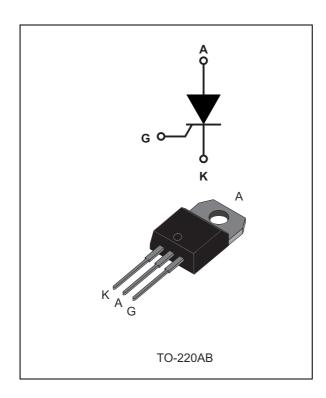


TN1610H-6T



High temperature 16 A SCRs

Datasheet - production data



Description

Thanks to a junction temperature T_j up to 150 °C and a non-isolated TO-220 package, the TN1610H-6T offers high thermal performance operation up to 16 A rms.

The trade-off between the device's noise immunity (dV/dt = 1 kV/ μ s), its gate triggering current (I_{GT} = 10 mA) and its turn-on current rise (dI/dt = 100 A/ μ s) allows the design of robust and compact control circuits for voltage regulators in motorbikes and industrial drives, overvoltage crowbar protection, motor control circuits in power tools and kitchen appliances and inrush current limiting circuits.

Table 1. Device summary

Order code	Package	V _{DRM} /V _{RRM}	I _{GT}
TN1610H-6T	TO-220AB	600 V	10 mA

Features

- High junction temperature: T_i = 150 °C
- High noise immunity dV/dt = 1000 V/μs up to 150 °C
- Gate triggering current I_{GT} = 10 mA
- Blocking voltage V_{DRM}/V_{RRM} = 600 V
- High turn on current rise dl/dt: 100 A/μs
- ECOPACK[®]2 compliant component

Applications

- · Voltage regulator circuits for motorbikes
- · Inrush current limiting circuits
- · Motor control circuits and starters
- Light dimmers
- Solid state relays

Characteristics TN1610H-6T

1 Characteristics

Table 2. Absolute ratings

Symbol	Parameter	Value	Unit			
I _{T(RMS)}	On-state rms current (180° conduction a	T _c = 133 °C	16	Α		
		T _c = 133 °C	10	Α		
I _{T(AV)}	Average on-state current (180° conduction	T _c = 138 °C	8			
			T _c = 142 °C	6		
l	Non repetitive surge peak on-state current (T _j initial = 25 °C)		t = 8.3 ms	153	A	
ITSM			t = 10 ms	140		
l ² t	I^2 t value for fusing (T_j initial = 25 °C)	$t_p = 10 \text{ ms}$	98	A ² s		
dl/dt	Critical rate of rise of on-state current $I_G = 2 \times I_{GT}$, $t_r \le 100$ ns, $T_j = 25$ °C		F = 60 Hz	100	A/μs	
V _{DRM} , V _{RRM}	Repetitive peak off-state voltage			600	٧	
I_{GM}	Peak gate current $t_p = 20 \mu s$		T _j = 150 °C	4	Α	
P _{G(AV)}	Average gate power dissipation	1	W			
T _{stg} T _j	Storage junction temperature range Operating junction temperature range			- 40 to + 150 - 40 to + 150	°C	
T _L	Maximum lead temperature for soldering during 10 s			260	°C	

Table 3. Electrical characteristics (T_j = 25 °C, unless otherwise specified)

Symbol	Test conditions	Value	Unit		
1.	$V_D = 12 \text{ V}, R_L = 33 \Omega$		Тур.	4.5	mA
I _{GT}			Max.	10	IIIA
V _{GT}	$V_D = 12 \text{ V}, R_L = 33 \Omega$	V_D = 12 V, R_L = 33 Ω			V
$V_{\sf GD}$	$V_D = V_{DRM}, R_L = 3.3 \text{ k}\Omega$ $T_j = 150 \text{ °C}$		Min.	0.2	V
I _H	I _T = 500 mA, gate open			30	mA
ΙL	$I_G = 1.2 \times I_{GT}$		Max.	60	mA
dV/dt	$V_D = 402 \text{ V, gate open}$ $T_j = 150 \text{ °C}$		Min.	1000	V/µs
t _{gt}	$I_T = 32 \text{ A}, V_D = 600 \text{ V}, I_G = 100 \text{ mA},$ $(dI_G/dt)max = 0.2 \text{ A}/\mu\text{s}$		Тур	1.9	μѕ
t _q	$V_D = 402 \text{ V}, \ V_R = 25 \text{ V}, \ I_T = 16 \text{ A}, \\ (dI_G/dt) max = 30 \text{ A/}\mu\text{s}, \ dV_D/dt = 40 \text{ V/}\mu\text{s} $ $T_j = 150 \text{ °C}$		Тур	70	μs

TN1610H-6T Characteristics

Table 4. Static characteristics

Symbol	Test conditions			Value	Unit
V_{TM}	$I_{TM} = 32 \text{ A}, t_p = 380 \mu\text{s}$	T _j = 25 °C	Max.	1.6	V
V _{t0}	Threshold voltage	T _j = 150 °C	Max.	0.82	V
R _d	Dynamic resistance	T _j = 150 °C	Max.	25	mΩ
I_{DRM} , I_{RRM} $V_D = V_{DRM}$, $V_R = V_{RRM}$	V V V	T _j = 25 °C	Max.	5	μΑ
	VD = VDRM, VR = VRRM	T _j = 150 °C	IVIAX.	1.5	mA

Table 5. Thermal resistance

Symbol	Parameter	Value	Unit
R _{th(j-c)}	Junction to case (AC)	1.1	°C/W
R _{th(j-a)}	Junction to ambient (DC)	60	°C/W

Figure 1. Maximum power dissipation versus average on-state current

Figure 2. Average and DC on-state current versus case temperature

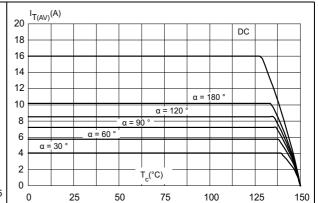
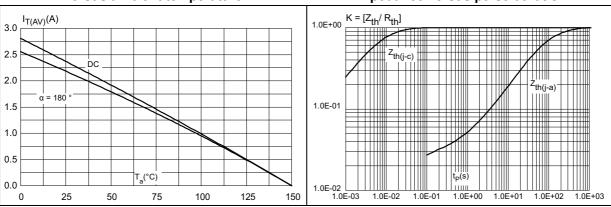


Figure 3. Average and DC on-state current versus ambient temperature

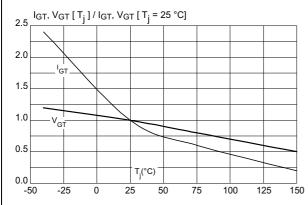
Figure 4. Relative variation of thermal impedance versus pulse duration



Characteristics TN1610H-6T

Figure 5. Relative variation of gate triggering current and gate voltage versus junction temperature (typical values)

Figure 6. Relative variation of holding current and latching current versus junction temperature (typical values)



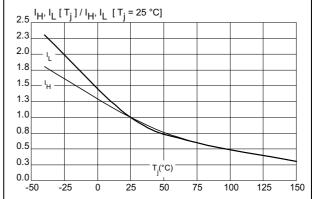
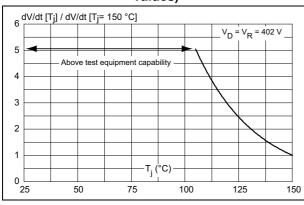


Figure 7. Relative variation of static dV/dt immunity versus junction temperature (typical values)

Figure 8. Surge peak on-state current versus number of cycles



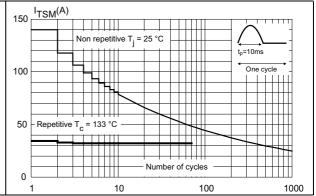
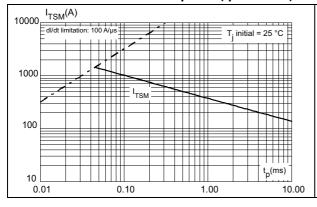
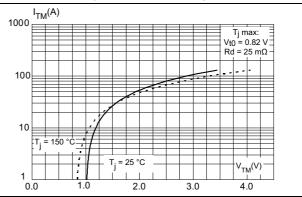


Figure 9. Non-repetitive surge peak on-state current for a sinusoidal pulse (tp < 10 ms)

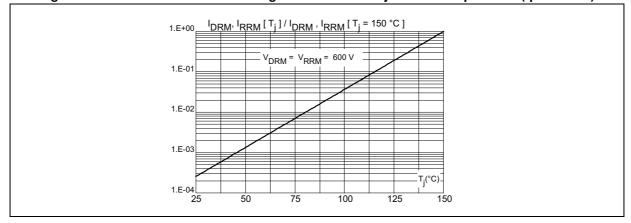
Figure 10. On-state characteristics (maximum values)





TN1610H-6T Characteristics

Figure 11. Relative variation of leakage current versus junction temperature (tp < 10 ms)



Package information TN1610H-6T

2 Package information

- Epoxy meets UL94, V0
- Lead-free package
- Halogen free molding compound
- Recommended torque: 0.4 to 0.6 N·m

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK[®] packages, depending on their level of environmental compliance. ECOPACK[®] specifications, grade definitions and product status are available at: www.st.com. ECOPACK[®] is an ST trademark.

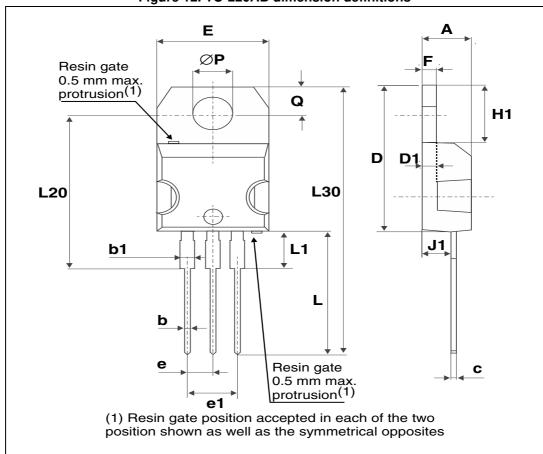


Figure 12. TO-220AB dimension definitions

TN1610H-6T Package information

Table 6. TO-220AB dimension values

			Dime	nsions		
Ref.		Millimeters			Inches	
	Min.	Тур.	Max.	Min.	Тур.	Max.
Α	15.20		15.90	0.598		0.625
a1		3.75			0.147	
a2	13.00		14.00	0.511		0.551
В	10.00		10.40	0.393		0.409
b1	0.61		0.88	0.024		0.034
b2	1.23		1.32	0.048		0.051
С	4.40		4.60	0.173		0.181
c1	0.49		0.70	0.019		0.027
c2	2.40		2.72	0.094		0.107
е	2.40		2.70	0.094		0.106
F	6.20		6.60	0.244		0.259
ØI	3.75		3.85	0.147		0.151
14	15.80	16.40	16.80	0.622	0.646	0.661
L	2.65		2.95	0.104		0.116
12	1.14		1.70	0.044		0.066
13	1.14		1.70	0.044		0.066
М		2.60			0.102	

Ordering information TN1610H-6T

3 Ordering information

Figure 13. Ordering information scheme

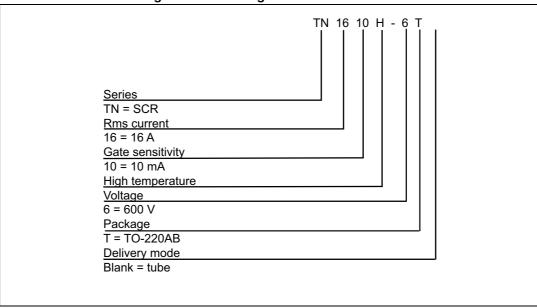


Table 7. Ordering information

Order code	Marking	Package	Weight	Base qty	Delivery mode
TN1610H-6T	TN1610H6	TO-220AB	2.3 g	50	Tube

4 Revision history

Table 8. Document revision history

Date	Revision	Changes
24-Feb-2015	1	Initial release.

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